

Atty Dckt Number: 2102397-991220

PATENT

- 1 -

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Chern et al.

Application No. 10/008,204

Filed: December 5, 2001

For: METHOD OF FORMING DIFFERENT
OXIDE THICKNESS FOR HIGH
VOLTAGE TRANSISTOR AND
MEMORY CELL TUNNEL DIELECTRIC

Group Art Unit: 2826

Examiner: Pershelle L. Greene

RESPONSE TO OFFICE ACTION
MAILED JULY 24, 2002

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#7/A
Amend
Election
J. M. Amador
9/6/02

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to Box Non-Fee Amendment, Assistant Commissioner for Patents, Washington, DC 20231, on August 15, 2002.

GRAY CARY WARE & FREIDENRICH Date: 8/15/02

By: Kathleen LaBrie
Kathleen LaBrie

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action mailed on July 24, 2002, please amend the above identified application as follows:

I. CLEAN VERSION OF CLAIMS AMENDED AND ADDED

A. Please cancel claims 15-27 without prejudice.

RECEIVED
AUG 29 2002
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